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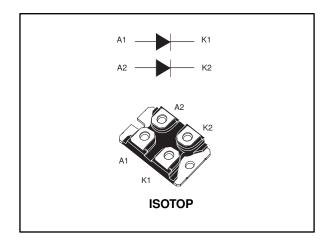




STTH120L06TV

Turbo 2 ultrafast high voltage rectifier

Datasheet - production data



Features

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses
- Insulated package ISOTOP:
 - Insulated voltage: 2500 V_{RMS} sine

Description

This device that uses ST Turbo 2 600 V technology, is specially suited for use in switching power supplies, and industrial applications, as rectification and freewheeling diode.

Table 1: Device summary

Symbol	Value
I _{F(AV)}	2 x 60 A
V_{RRM}	600 V
T _j (max.)	150 °C
V _F (typ.)	0.95 V
t _{rr} (max.)	70 ns



TM: ISOTOP is a trademark of STMicroelectronics

Characteristics STTH120L06TV

1 Characteristics

Table 2: Absolute ratings (limiting values, per diode)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	600	V	
I _{F(RMS)}	Forward rms current 120			
I _{F(AV)}	Average forward current, δ = 0.5 T_C = 65 °C, per diode		60	Α
I _{FSM}	Surge non repetitive forward current	500	Α	
T _{stg}	Storage temperature range -55 to +150 °C			
Tj	Maximum operating junction temperature 150 °C			

Table 3: Thermal parameters

Symbol	Parameter		Maximum values	Unit
D	Junction to case	Per diode	0.98	
R _{th(j-c)}	Junction to case	Total	0.54	°C/W
R _{th(c)}	R _{th(c)} Coupling		0.1	

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j} \left(\text{diode1} \right) = P_{\left(\text{diode1} \right)} \, x \, R_{th\left(j\text{-}c \right)} \left(\text{per diode} \right) \, + \, P_{\left(\text{diode2} \right)} \, x \, R_{th\left(c \right)}$

Table 4: Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Doverse leeke se current	T _j = 25 °C	$V_{\text{R}} = V_{\text{RRM}}$	-		50	μА
IR ^(*)	Reverse leakage current	T _j = 125 °C		1	50	500	
V _F (2)	Converd voltage drap	T _j = 25 °C	I- 60 A	-		1.55	V
V F ⁽²⁾	V _F ⁽²⁾ Forward voltage drop		I _F = 60 A	-	0.95	1.20	V

Notes:

 $^{(1)}$ Pulse test: t_p = 5 ms, δ < 2%

(2) Pulse test: t_p = 380 μs, δ < 2%

To evaluate the maximum conduction losses, use the following equation:

 $P = 0.93 \text{ x } I_{F(AV)} + 0.0045 \text{ x } I_{F^2(RMS)}$

STTH120L06TV Characteristics

Table 5: Dynamic characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
	Poverse receivery time	T. 25 °C	$I_F = 0.5 A,$ $I_{rr} = 0.25 A,$ $I_R = 1 A$	ı		70	20
t _{rr} Reverse recovery time	T _j = 25 °C	$I_F = 1 A,$ $dI_F/dt = 50 A/\mu s,$ $V_R = 30 V$	ı	75	105	ns	
I _{RM}	Reverse recovery current	T _j = 125 °C	I _F = 60 A, dI _F /dt = 400 A/µs, dI _F /dt = 100 A/µs	-	14	19	Α
t _{fr} Forward recovery time		T _j = 25 °C	I _F = 60 A, dI _F /dt = 200 A/µs V _{FR} = 1.1 x V _{Fmax}	1		500	ns
V _{FP}	Forward recovery voltage	T _j = 25 °C	I _F = 60 A, dI _F /dt = 200 A/µs V _{FR} = 1.1 x V _{Fmax}	-	3		٧

Characteristics STTH120L06TV

1.1 Characteristics (curves)

Figure 1: Conduction losses versus average

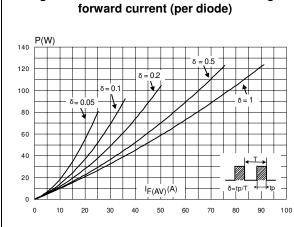


Figure 2: Forward voltage drop versus forward current (per diode)

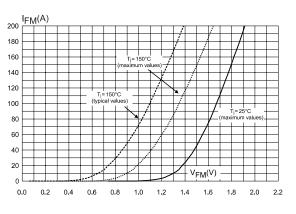


Figure 3: Relative variation of thermal impedance junction to case versus pulse duration

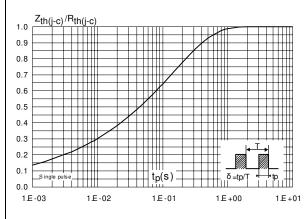


Figure 4: Peak reverse recovery current versus dl_F/dt (typical values, per diode)

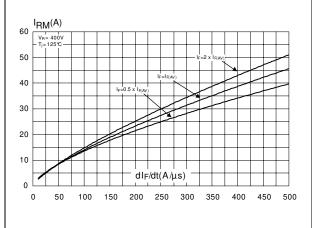


Figure 5: Reverse recovery time versus dl_F/dt (typical values, per diode)

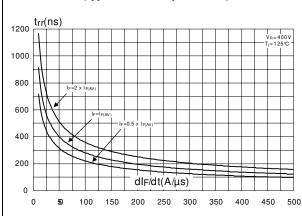
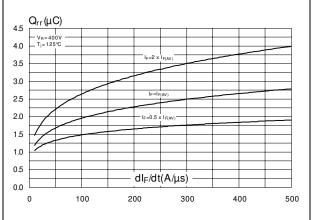


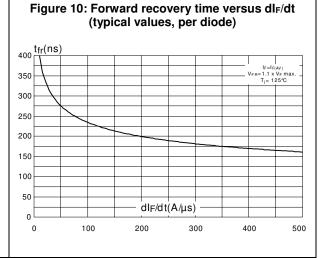
Figure 6: Reverse recovery charges versus dl_F/dt (typical values, per diode)

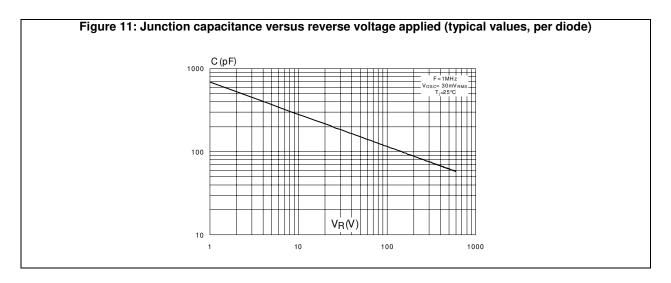


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Figure 7: Reverse recovery softness factor versus dl_F/dt (typical values, per diode) Sfactor 1.6 1.4 12 1.0 8.0 0.6 0.4 02 $dI_F/dt(A/\mu s)$ 0.0 0 100 150 200 250 300 350 400

Figure 8: Relative variations of dynamic parameters versus junction temperature 1.4 1.2 1.0 8.0 0.6 I_F=I_{F(AV)} – V_R= 400V Reference: T_j= 125° C 0.4 0.2 T_j(°C) 0.0 25 50 75 100 125





Package information STTH120L06TV

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

• Epoxy meets UL94, V0

Cooling method: by conduction (C)
 Recommended torque value: 1.3 N·m
 Maximum torque value: 1.5 N·m

STMicroelectronics strongly recommend the use of the screws delivered with this product.

The use of any other screws is entirely at the user's own risk and will invalidate the warranty.

2.1 ISOTOP package information

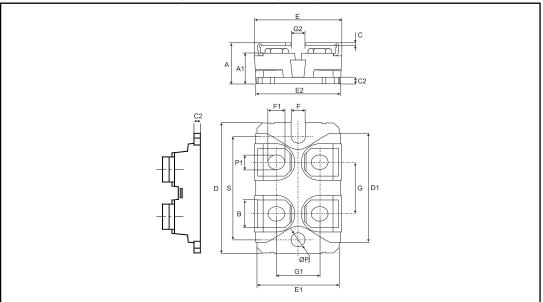


Figure 12: ISOTOP package outline

Table 6: ISOTOP package mechanical data

	Dimensions					
Ref.	Millim	neters	Inches			
	Min.	Max.	Min.	Max.		
Α	11.80	12.20	0.460	0.480		
A1	8.90	9.10	0.350	0.358		
В	7.80	8.20	0.307	0.323		
С	0.75	0.85	0.030	0.033		
C2	1.95	2.05	0.077	0.081		
D	37.80	38.20	1.488	1.504		
D1	31.50	31.70	1.240	1.248		
Е	25.15	25.50	0.990	1.004		
E1	23.85	24.15	0.939	0.951		
E2	24.80		0.9	976		
G	14.90	15.10	0.587	0.594		
G1	12.60	12.80	0.496	0.504		
G2	3.50	4.30	0.138	0.169		
F	4.10	4.30	0.161	0.169		
F1	4.60	5	0.181	0.197		
Diam P	4	4.30	0.157	0.69		
P1	4	4.40	0.157	0.173		
S	30.10	30.30	1.185	1.193		

Ordering information STTH120L06TV

3 Ordering information

Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STTH120L06TV1	STTH120L06TV1	ISOTOP	27 g (without screws)	10 (with screws)	Tube

4 Revision history

Table 8: Document revision history

Date	Revision	Changes
07-Sep-2004	1	First issue.
04-Apr-2011	2	Updated Chapter 2: Package information
20-Jan-2017	3	Updated Section "Features" and Section 2.2: "ISOTOP package information".

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